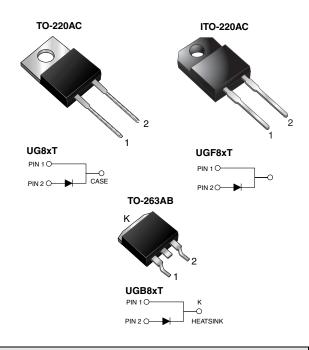


UG(F,B)8HT & UG(F,B)8JT

Vishay General Semiconductor

High Voltage Ultrafast Rectifier



PRIMARY CHARACTERISTICS					
I _{F(AV)}	8 A				
V _{RRM}	500 V, 600 V				
I _{FSM}	100 A				
t _{rr}	25 ns				
t _{fr}	500 ns				
V _F	1.5 V				
T _J max.	150 °C				

FEATURES

- Glass passivated chip junction
- Ultrafast recovery time
- Soft recovery characteristics
- Low switching losses, high efficiency
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AC and ITO-220AC package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high voltage and high frequency power factor correction application.

MECHANICAL DATA

Case: TO-220AC, ITO-220AC, TO-263AB Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	UG8HT	UG8JT	UNIT		
Maximum repetitive peak reverse voltage	V _{RRM}	500	600	V		
Maximum working reverse voltage	V _{RWM}	400	480	V		
Maximum RMS voltage	V _{RMS}	350	420	V		
Maximum DC blocking voltage	V _{DC}	500	600	V		
Maximum average forward rectified current	I _{F(AV)}	8.0		А		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	100		A		
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150		°C		
Isolation voltage (ITO-220AB only) from terminals to heatsink t = 1 min	V _{AC}	1500		v		



COMPLIANT

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ELECTRICAL CHARACTERISTICS ($T_C = 25$ °C unless otherwise noted)							
PARAMETER	TEST CO	ONDITIONS	SYMBOL	UG8HT	UG8JT	UNIT	
Maximum instantaneous forward voltage ⁽¹⁾	I _F = 8 A I _F = 8 A	T _J = 25 °C T _J = 125 °C	V _F	1.75 1.50		v	
Maximum DC reverse current at V _{RWM}		T _J = 25 °C T _J = 100 °C T _J = 125 °C	I _R	3 80 4.		μA μA mA	
Mariana ana ara-	I _F = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A		t _{rr}	25		ns	
Maximum reverse recovery time	I _F = 1.0 A, d V _R = 30 V, I ₁	l/dt = 50 A/μs, _r = 0.1 I _{RM}	t _{rr}	5	0	ns	
Typical softness factor (t _b /t _a)	$I_F = 8.0 \text{ A}, \text{ dI/dt} = 240 \text{ A/}\mu\text{s},$ $V_R = 400 \text{ V}, I_{rr} = 0.1 \text{ I}_{RM}$		S	1.0		-	
I _F = 8.0 A, dl/dt = 64 A/µs V _R = 400 V, T _C = 125 °C			I _{RM}	5.5		A	
Maximum reverse recovery current	$I_F = 8.0 \text{ A}, \text{ dI/dt} = 240 \text{ A/}\mu\text{s},$ $V_R = 400 \text{ V}, \text{ T}_C = 125 \text{ °C}$		I _{RM}	10		A	
Peak forward recovery time	$I_F = 8.0 \text{ A}, \text{ dI/dt} = 64 \text{ A/}\mu\text{s},$ $V_F = 1.1 \text{ x } V_F \text{ max}.$		t _{fr}	500		ns	

Note:

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	UG8	UGF	UGB8	UNIT
Typical thermal resistance from junction to case	$R_{ ext{ heta}JC}$	2.2	5.0	2.2	°C/W

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AC	UG8JT-E3/45	1.80	45	50/tube	Tube		
ITO-220AC	UGF8JT-E3/45	1.95	45	50/tube	Tube		
TO-263AB	UGB8JT-E3/45	1.33	45	50/tube	Tube		
TO-263AB	UGB8JT-E3/81	1.33	81	800/reel	Tape and reel		
TO-220AC	UG8JTHE3/45 ⁽¹⁾	1.80	45	50/tube	Tube		
ITO-220AC	UGF8JTHE3/45 ⁽¹⁾	1.95	45	50/tube	Tube		
TO-263AB	UGB8JTHE3/45 ⁽¹⁾	1.33	45	50/tube	Tube		
TO-263AB	UGB8JTHE3/81 ⁽¹⁾	1.33	81	800/reel	Tape and reel		

Note:

(1) Automotive grade AEC Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

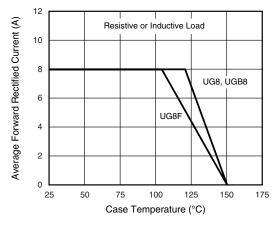


Figure 1. Maximum Forward Current Derating Curve

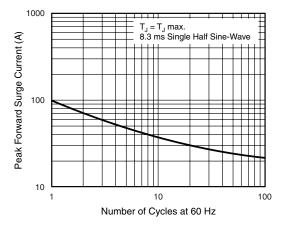


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current

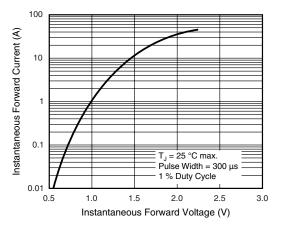


Figure 3. Typical Instantaneous Forward Characteristics

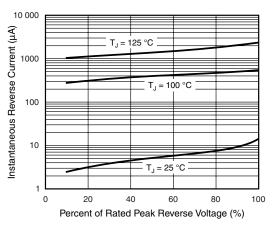


Figure 4. Typical Reverse Leakage Characteristics

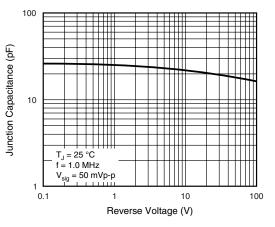


Figure 5. Typical Junction Capacitance

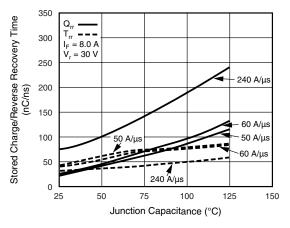


Figure 6. Reverse Switching Characteristics

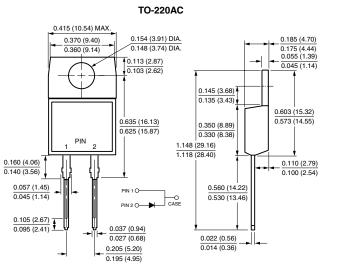
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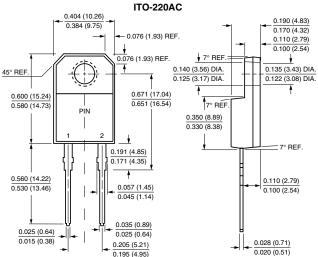
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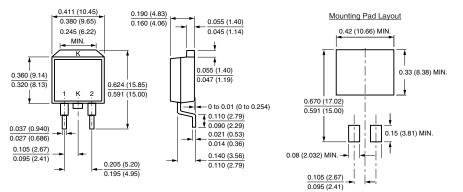


PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





TO-263AB





Vishay

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